FORM PTO-1449
LIST OF PATENTS AND
APPLICANT'S INPORMATION DISCLOSURE STATEMENT

ATTORNEY DOCKET NO.: 7822702FLP

SERIAL NO.: 10/736,859

APPLICANT: Yao

JAN 2 0 200 GROUP: Unknown 2812

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER

DOCUMENT

DATE

NAME

CLASS SUB

FILING IF

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EXAMINER INITIALS		DOCUMENT NUMBER	DATE	NAME .	CLASS	SUB CLASS	FILING IF APPROPRIATE
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	АН						
	AI						

FOREIGN PATENT DOCUMENTS							
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION Yes No	
744							
AN							
AO							
AP							
QA							

		OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)	
TD	A R	Yao, Jie et al., <u>Bandwidth Simulations Of 10 Gb/s Avalanche Photodiodes</u> , IEEE, pp. 699 - 700.	
	S		

EXAMINER:	/Thu Huong Dinh/	DATE CONSIDERED:	09/19/2006	
			08/18/2006	

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; * Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Form PTO 1449	ATTY. DOCKET NUMBER:	SERIAL NUMBER:
U.S. Department of Commerce Patent and Trademark Office Information Disclosure Statement by Applicant	78227CIP1p1510 US CIP	New Application
	APPLICANT:	<u> </u>
_	YAO .	·
·	FILING DATE: 12/16/2003	GROUP:
	NEW APPLICATION	NEW APPLICATION

U.S. Patent Documents

EXAMINER INTRAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCL. ASS	FILE
מיד	A .	Ishibashi et al	Oct 6, 1998	5,818,096	257/458		
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Foreign Patent Documents

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SURCLASS	TRAN	SLATION
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TD	С	Shimizu et al., "InP-InGaAs Uni-Traveling-Carrier Photodiode With Improved 3-dB Bandwidt of Over 150 GH2", IEEE Photonics Technology Letters, Vol. 10, No. 3, March 1998, Pages 412-414.						
- TD	D	Kato et al., "Design of Ultrawide-Band Lightwave Technology, Vol. 8, Issue 4,	l, High Sensitivity 1990, pp. 531-537	p-i-n Photodetectors", Journal of 7.				
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	G	S.M. Sze, Semiconductor Devices Physic	cs and Technolog	y, p. 283.				
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